



## 3 – DC and Power Characteristics

### General Specifications

#### Operating Conditions

Stresses beyond those listed in Table 3-1 may cause permanent damage to the device.

Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Devices should not be operated outside the recommended operating ranges specified in Table 3-2 on page 3-3.

Table 3-1 • Absolute Maximum Ratings

Symbol	Parameter	Commercial	Industrial	Units
V <sub>CC</sub>	DC core supply voltage	-0.3 to 1.65	-0.3 to 1.65	V
V <sub>JTAG</sub>	JTAG DC voltage	-0.3 to 3.75	-0.3 to 3.75	V
V <sub>PUMP</sub>	Programming voltage	-0.3 to 3.75	-0.3 to 3.75	V
V <sub>CCPLL</sub>	Analog power supply (PLL)	-0.3 to 1.65	-0.3 to 1.65	V
V <sub>CCI</sub>	DC I/O output buffer supply voltage	-0.3 to 3.75	-0.3 to 3.75	V
V <sub>I</sub>	I/O input voltage <sup>1</sup>	-0.3 V to 3.6 V (when I/O hot insertion mode is enabled) -0.3 V to (V <sub>CCI</sub> + 1 V) or 3.6 V, whichever voltage is lower (when I/O hot-insertion mode is disabled)		V
V <sub>CC33A</sub>	+3.3 V power supply	-0.3 to 3.75 <sup>2</sup>	-0.3 to 3.75 <sup>2</sup>	V
V <sub>AREF</sub>	Voltage reference for ADC	-0.3 to 3.75	-0.3 to 3.75	V
V <sub>CC15A</sub>	Digital power supply for the analog system	-0.3 to 1.65	-0.3 to 1.65	V
V <sub>CCNVM</sub>	Embedded flash power supply	-0.3 to 1.65	-0.3 to 1.65	V
V <sub>CCOSC</sub>	Oscillator power supply	-0.3 to 3.75	-0.3 to 3.75	V
AV, AC	Unpowered, ADC reset asserted or unconfigured	-11.0 to 12.6	-11.0 to 12.4	V
	Analog input (+16 V to +2 V prescaler range)	-0.4 to 12.6	-0.4 to 12.4	V
	Analog input (+1 V to +0.125 V prescaler range)	-0.4 to 3.75	-0.4 to 3.75	V
	Analog input (-16 V to -2 V prescaler range)	-11.0 to 0.4	-11.0 to 0.4	V
	Analog input (-1 V to -0.125 V prescaler range)	-3.75 to 0.4	-3.75 to 0.4	V

Notes:

1. The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in Table 3-4 on page 3-4.
2. Analog data not valid beyond 3.65 V.
3. For flash programming and retention maximum limits, refer to Table 3-5 on page 3-5. For recommended operating limits refer to Table 3-2 on page 3-3.



**Table 3-1 • Absolute Maximum Ratings (continued)**

Symbol	Parameter	Commercial	Industrial	Units
	Analog input (direct input to ADC)	-0.4 to 3.75	-0.4 to 3.75	V
	Digital input	-0.4 to 12.6	-0.4 to 12.4	V
AG	Unpowered, ADC reset asserted or unconfigured	-11.0 to 12.6	-11.0 to 12.4	V
	Low Current Mode (1 $\mu$ A, 3 $\mu$ A, 10 $\mu$ A, 30 $\mu$ A)	-0.4 to 12.6	-0.4 to 12.4	V
	Low Current Mode (-1 $\mu$ A, -3 $\mu$ A, -10 $\mu$ A, -30 $\mu$ A)	-11.0 to 0.4	-11.0 to 0.4	V
	High Current Mode <sup>3</sup>	-11.0 to 12.6	-11.0 to 12.4	V
AT	Unpowered, ADC reset asserted or unconfigured	-0.4 to 16.5	-0.4 to 16.0	V
	Analog input (+16 V, 4 V prescaler range)	-0.4 to 16.5	-0.4 to 16.0	V
	Analog input (direct input to ADC)	-0.4 to 3.75	-0.4 to 3.75	V
	Digital input	-0.4 to 16.5	-0.4 to 16.0	V
T <sub>STG</sub> <sup>3</sup>	Storage temperature	-65 to +150		°C
T <sub>J</sub> <sup>3</sup>	Junction temperature	+125		°C

**Notes:**

1. The device should be operated within the limits specified by the datasheet. During transitions, the input signal may undershoot or overshoot according to the limits shown in [Table 3-4 on page 3-4](#).
2. Analog data not valid beyond 3.65 V.
3. For flash programming and retention maximum limits, refer to [Table 3-5 on page 3-5](#). For recommended operating limits refer to [Table 3-2 on page 3-3](#).

**Table 3-2 • Recommended Operating Conditions**

Symbol	Parameter	Commercial	Industrial	Units	
$T_A, T_J$	Ambient and junction temperature	0 to +70	-40 to +85	°C	
$V_{CC}$	1.5 V DC core supply voltage	1.425 to 1.575	1.425 to 1.575	V	
$V_{JTAG}$	JTAG DC voltage	1.4 to 3.6	1.4 to 3.6	V	
$V_{PUMP}$	Programming voltage	Programming mode	3.15 to 3.45	3.15 to 3.45	V
		Operation <sup>3</sup>	0 to 3.6	0 to 3.6	V
$V_{CCPLL}$	Analog power supply (PLL)	1.425 to 1.575	1.425 to 1.575	V	
$V_{CCI}$	1.5 V DC supply voltage	1.425 to 1.575	1.425 to 1.575	V	
	1.8 V DC supply voltage	1.7 to 1.9	1.7 to 1.9	V	
	2.5 V DC supply voltage	2.3 to 2.7	2.3 to 2.7	V	
	3.3 V DC supply voltage	3.0 to 3.6	3.0 to 3.6	V	
	LVDS differential I/O	2.375 to 2.625	2.375 to 2.625	V	
	LVPECL differential I/O	3.0 to 3.6	3.0 to 3.6	V	
$V_{CC33A}$	+3.3 V power supply	2.97 to 3.63	2.97 to 3.63	V	
$V_{AREF}$	Voltage reference for ADC	2.527 to 2.593	2.527 to 2.593	V	
$V_{CC15A}$ <sup>6</sup>	Digital power supply for the analog system	1.425 to 1.575	1.425 to 1.575	V	
$V_{CCNVM}$	Embedded flash power supply	1.425 to 1.575	1.425 to 1.575	V	
$V_{CCOSC}$	Oscillator power supply	2.97 to 3.63	2.97 to 3.63	V	
$AV, AC$ <sup>4</sup>	Unpowered, ADC reset asserted or unconfigured	-10.5 to 12.0	-10.5 to 12.0	V	
	Analog input (+16 V to +2 V prescaler range)	-0.3 to 12.0	-0.3 to 12.0	V	
	Analog input (+1 V to +0.125 V prescaler range)	-0.3 to 3.6	-0.3 to 3.6	V	
	Analog input (-16 V to -2 V prescaler range)	-10.5 to 0.3	-10.5 to 0.3	V	
	Analog input (-1 V to -0.125 V prescaler range)	-3.6 to 0.3	-3.6 to 0.3	V	
	Analog input (direct input to ADC)	-0.3 to 3.6	-0.3 to 3.6	V	
	Digital input	-0.3 to 12.0	-0.3 to 12.0	V	
$AG$ <sup>4</sup>	Unpowered, ADC reset asserted or unconfigured	-10.5 to 12.0	-10.5 to 12.0	V	
	Low Current Mode (1 $\mu$ A, 3 $\mu$ A, 10 $\mu$ A, 30 $\mu$ A)	-0.3 to 12.0	-0.3 to 12.0	V	
	Low Current Mode (-1 $\mu$ A, -3 $\mu$ A, -10 $\mu$ A, -30 $\mu$ A)	-10.5 to 0.3	-10.5 to 0.3	V	
	High Current Mode <sup>5</sup>	-10.5 to 12.0	-10.5 to 12.0	V	
$AT$ <sup>4</sup>	Unpowered, ADC reset asserted or unconfigured	-0.3 to 16.0	-0.3 to 15.5	V	
	Analog input (+16 V, +4 V prescaler range)	-0.3 to 16.0	-0.3 to 15.5	V	
	Analog input (direct input to ADC)	-0.3 to 3.6	-0.3 to 3.6	V	
	Digital input	-0.3 to 16.0	-0.3 to 15.5	V	

**Notes:**

1. The ranges given here are for power supplies only. The recommended input voltage ranges specific to each I/O standard are given in Table 2-82 on page 2-162.
2. All parameters representing voltages are measured with respect to GND unless otherwise specified.
3.  $V_{PUMP}$  can be left floating during normal operation (not programming mode).
4. The input voltage may overshoot by up to 500 mV above the Recommended Maximum (150 mV in Direct mode), provided the duration of the overshoot is less than 50% of the operating lifetime of the device.
5. The AG pad should also conform to the limits as specified in Table 2-45 on page 2-115.
6. Violating the  $V_{CC15A}$  recommended voltage supply during an embedded flash program cycle can corrupt the page being programmed.

**Table 3-3 • Input Resistance of Analog Pads**

Pads	Pad Configuration	Prescaler Range	Input Resistance to Ground
AV, AC	Analog Input (direct input to ADC)	+16 V to +2 V	1 M $\Omega$ (typical)
		+1 V to +0.125 V	> 10 M $\Omega$
	Analog Input (positive prescaler)	+16 V to +2 V	1 M $\Omega$ (typical)
		+1 V to +0.125 V	> 10 M $\Omega$
	Analog Input (negative prescaler)	-16 V to -2 V	1 M $\Omega$ (typical)
		-1 V to -0.125 V	> 10 M $\Omega$
	Digital input	+16 V to +2 V	1 M $\Omega$ (typical)
	Current monitor	+16 V to +2 V	1 M $\Omega$ (typical)
-16 V to -2 V		1 M $\Omega$ (typical)	
AT	Analog Input (direct input to ADC)	+16 V, +4 V	1 M $\Omega$ (typical)
	Analog Input (positive prescaler)	+16 V, +4 V	1 M $\Omega$ (typical)
	Digital input	+16 V, +4 V	1 M $\Omega$ (typical)
	Temperature monitor	+16 V, +4 V	> 10 M $\Omega$

**Table 3-4 • Overshoot and Undershoot Limits <sup>1</sup>**

V <sub>CC1</sub>	Average V <sub>CC1</sub> -GND Overshoot or Undershoot Duration as a Percentage of Clock Cycle <sup>2</sup>	Maximum Overshoot/Undershoot <sup>2</sup>
2.7 V or less	10%	1.4 V
	5%	1.49 V
3.0 V	10%	1.1 V
	5%	1.19 V
3.3 V	10%	0.79 V
	5%	0.88 V
3.6 V	10%	0.45 V
	5%	0.54 V

**Notes:**

1. Based on reliability requirements at 85°C.
2. The duration is allowed at one cycle out of six clock cycle. If the overshoot/undershoot occurs at one out of two cycles, the maximum overshoot/undershoot has to be reduced by 0.15 V.

**Table 3-5 • FPGA Programming, Storage, and Operating Limits**

Product Grade	Element	Grade Programming Cycles	Retention	Storage Temperature (°C)	
				Minimum	Maximum
Commercial	FPGA/FlashROM	500	20 years <sup>2</sup>	0	85
	Embedded Flash	1 k	20 years <sup>2</sup>	0	85
		15 k	5 years <sup>2</sup>	0	85
Industrial	FPGA/FlashROM	500	20 years	-40	85
	Embedded Flash	1 k	20 years	-40	85
		15 k	5 years	-40	85

**Notes:**

1. This is a stress rating only. Functional operation at any condition other than those indicated is not implied.
2. If the embedded flash has been programmed less than 1 k times, every time it is programmed, the data will hold for 20 years. If the embedded flash has been programmed more than 1 k times but less than 15 k times, every time it is programmed, the data will hold for 5 years.

### I/O Power-Up and Supply Voltage Thresholds for Power-On Reset (Commercial and Industrial)

Sophisticated power-up management circuitry is designed into every Fusion device. These circuits ensure easy transition from the powered off state to the powered up state of the device. The many different supplies can power up in any sequence with minimized current spikes or surges. In addition, the I/O will be in a known state through the power-up sequence. The basic principle is shown in Figure 3-1 on page 3-6.

There are five regions to consider during power-up.

Fusion I/Os are activated only if ALL of the following three conditions are met:

1.  $V_{CC}$  and  $V_{CCI}$  are above the minimum specified trip points (Figure 3-1).
2.  $V_{CCI} > V_{CC} - 0.75\text{ V}$  (typical).
3. Chip is in the operating mode.

**$V_{CCI}$  Trip Point:**

Ramping up:  $0.6\text{ V} < \text{trip\_point\_up} < 1.2\text{ V}$

Ramping down:  $0.5\text{ V} < \text{trip\_point\_down} < 1.1\text{ V}$

**$V_{CC}$  Trip Point:**

Ramping up:  $0.6\text{ V} < \text{trip\_point\_up} < 1.1\text{ V}$

Ramping down:  $0.5\text{ V} < \text{trip\_point\_down} < 1\text{ V}$

$V_{CC}$  and  $V_{CCI}$  ramp-up trip points are about 100 mV higher than ramp-down trip points. This specifically built-in hysteresis prevents undesirable power-up oscillations and current surges. Note the following:

- During programming, I/Os become tristated and weakly pulled up to  $V_{CCI}$ .
- JTAG supply, PLL power supplies, and charge pump  $V_{PUMP}$  supply have no influence on I/O behavior.

### Internal Power-Up Activation Sequence

1. Core
2. Input buffers
3. Output buffers, after 200 ns delay from input buffer activation

### PLL Behavior at Brownout Condition

Actel recommends using monotonic power supplies or voltage regulators to ensure proper power-up behavior. Power ramp-up should be monotonic at least until  $V_{CC}$  and  $V_{CCPLX}$  exceed brownout activation levels. The  $V_{CC}$  activation level is specified as 1.1 V worst-case (see Figure 3-1 on page 3-6 for more details).

When PLL power supply voltage and/or  $V_{CC}$  levels drop below the  $V_{CC}$  brownout levels ( $0.75\text{ V} \pm 0.25\text{ V}$ ), the PLL output lock signal goes low and/or the output clock is lost. Refer to the *Power-Up/Down of Fusion FPGAs* application note for information on clock and lock recovery.

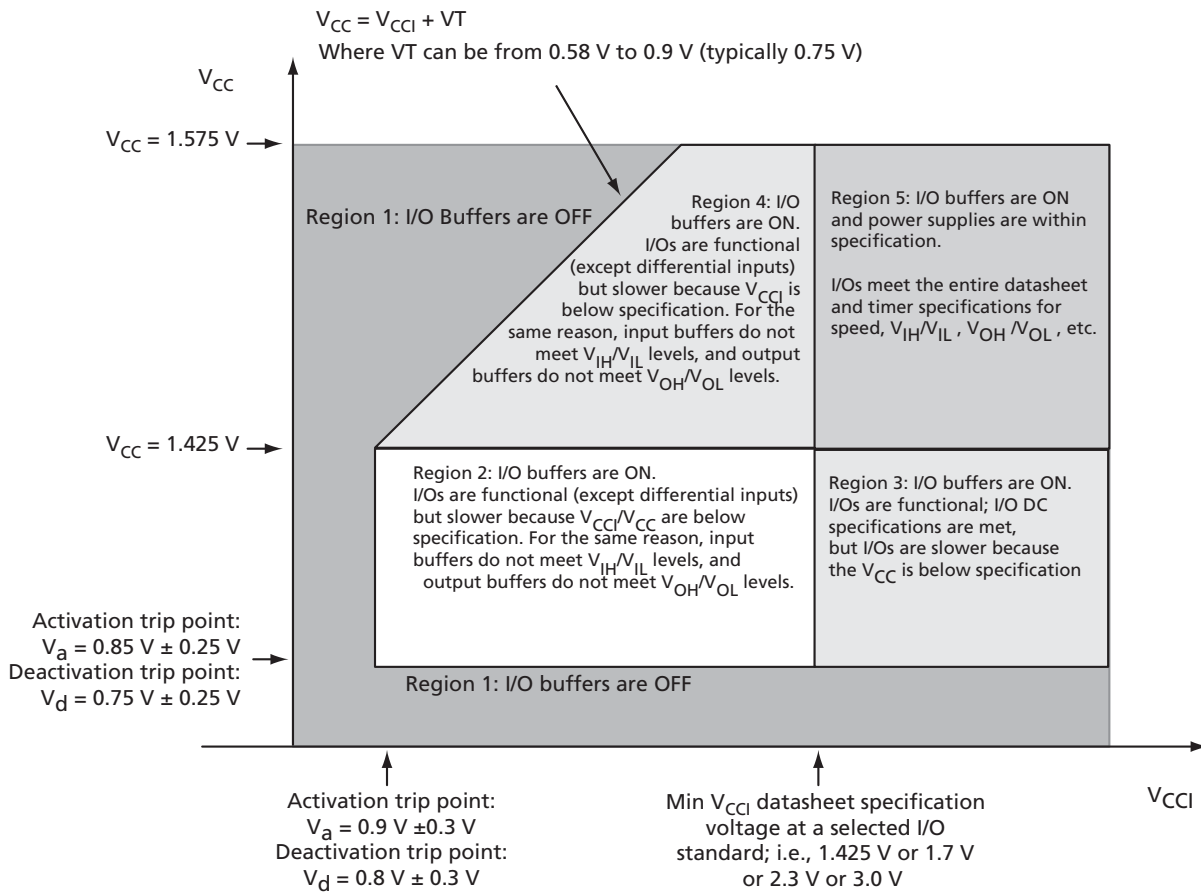


Figure 3-1 • I/O State as a Function of  $V_{CCI}$  and  $V_{CC}$  Voltage Levels

## Thermal Characteristics

### Introduction

The temperature variable in the Actel Designer software refers to the junction temperature, not the ambient, case, or board temperatures. This is an important distinction because dynamic and static power consumption will cause the chip's junction temperature to be higher than the ambient, case, or board temperatures. EQ 3-1 through EQ 3-3 give the relationship between thermal resistance, temperature gradient, and power.

$$\theta_{JA} = \frac{T_J - T_A}{P}$$

EQ 3-1

$$\theta_{JB} = \frac{T_J - T_B}{P}$$

EQ 3-2

$$\theta_{JC} = \frac{T_J - T_C}{P}$$

EQ 3-3

where

$\theta_{JA}$  = Junction-to-air thermal resistance

$\theta_{JB}$  = Junction-to-board thermal resistance

$\theta_{JC}$  = Junction-to-case thermal resistance

$T_J$  = Junction temperature

$T_A$  = Ambient temperature

$T_B$  = Board temperature (measured 1.0 mm away from the package edge)

$T_C$  = Case temperature

$P$  = Total power dissipated by the device

**Table 3-6 • Package Thermal Resistance**

Product	$\theta_{JA}$			$\theta_{JC}$	$\theta_{JB}$	Units
	Still Air	1.0 m/s	2.5 m/s			
U1AFS250-FG256	33.7	30.0	28.3	9.3	24.8	°C/W
U1AFS600-FG256	28.9	25.2	23.5	6.8	19.9	°C/W
U1AFS1500-FG256	23.3	19.6	18.0	4.3	14.2	°C/W

**Theta-JA**

Junction-to-ambient thermal resistance ( $\theta_{JA}$ ) is determined under standard conditions specified by JEDEC (JESD-51), but it has little relevance in actual performance of the product. It should be used with caution but is useful for comparing the thermal performance of one package to another.

A sample calculation showing the maximum power dissipation allowed for the U1AF5600-FG256 package under forced convection of 1.0 m/s and 75°C ambient temperature is as follows:

$$\text{Maximum Power Allowed} = \frac{T_{J(\text{MAX})} - T_{A(\text{MAX})}}{\theta_{JA}}$$

EQ 3-4

where

$$\theta_{JA} = 25.20^{\circ}\text{C/W} \text{ (taken from Table 3-6 on page 3-7).}$$

$$T_A = 75.00^{\circ}\text{C}$$

$$\text{Maximum Power Allowed} = \frac{110.00^{\circ}\text{C} - 75.00^{\circ}\text{C}}{25.2^{\circ}\text{C/W}} = 1.39 \text{ W}$$

The power consumption of a device can be calculated using the Actel power calculator. The device's power consumption must be lower than the calculated maximum power dissipation by the package. If the power consumption is higher than the device's maximum allowable power dissipation, a heat sink can be attached on top of the case, or the airflow inside the system must be increased.

**Theta-JB**

Junction-to-board thermal resistance ( $\theta_{JB}$ ) measures the ability of the package to dissipate heat from the surface of the chip to the PCB. As defined by the JEDEC (JESD-51) standard, the thermal resistance from junction to board uses an isothermal ring cold plate zone concept. The ring cold plate is simply a means to generate an isothermal boundary condition at the perimeter. The cold plate is mounted on a JEDEC standard board with a minimum distance of 5.0 mm away from the package edge.

**Theta-JC**

Junction-to-case thermal resistance ( $\theta_{JC}$ ) measures the ability of a device to dissipate heat from the surface of the chip to the top or bottom surface of the package. It is applicable for packages used with external heat sinks. Constant temperature is applied to the surface in consideration and acts as a boundary condition. This only applies to situations where all or nearly all of the heat is dissipated through the surface in consideration.

**Calculation for Heat Sink**

For example, in a design implemented in an U1AF5600-FG256 package with 2.5 m/s airflow, the power consumption value using the power calculator is 3.00 W. The user-dependent  $T_a$  and  $T_j$  are given as follows:

$$T_J = 110.00^{\circ}\text{C}$$

$$T_A = 70.00^{\circ}\text{C}$$

From the datasheet:

$$\theta_{JA} = 23.50^{\circ}\text{C/W}$$

$$\theta_{JC} = 6.80^{\circ}\text{C/W}$$

$$P = \frac{T_J - T_A}{\theta_{JA}} = \frac{110^{\circ}\text{C} - 70^{\circ}\text{C}}{23.50^{\circ}\text{C/W}} = 1.70 \text{ W}$$

EQ 3-5

The 1.70 W power is less than the required 3.00 W. The design therefore requires a heat sink, or the airflow where the device is mounted should be increased. The design's total junction-to-air thermal resistance requirement can be estimated by EQ 3-6:

$$\theta_{ja(\text{total})} = \frac{T_J - T_A}{P} = \frac{110^\circ\text{C} - 70^\circ\text{C}}{3.00 \text{ W}} = 13.33^\circ\text{C/W}$$

EQ 3-6

Determining the heat sink's thermal performance proceeds as follows:

$$\theta_{JA(\text{TOTAL})} = \theta_{JC} + \theta_{CS} + \theta_{SA}$$

EQ 3-7

where

$$\theta_{JA} = 0.37^\circ\text{C/W}$$

= Thermal resistance of the interface material between the case and the heat sink, usually provided by the thermal interface manufacturer

$$\theta_{SA} = \text{Thermal resistance of the heat sink in } ^\circ\text{C/W}$$

$$\theta_{SA} = \theta_{JA(\text{TOTAL})} - \theta_{JC} - \theta_{CS}$$

EQ 3-8

$$\theta_{SA} = 13.33^\circ\text{C/W} - 6.80^\circ\text{C/W} - 0.37^\circ\text{C/W} = 6.16^\circ\text{C/W}$$

A heat sink with a thermal resistance of 6.16°C/W or better should be used. Thermal resistance of heat sinks is a function of airflow. The heat sink performance can be significantly improved with increased airflow.

Carefully estimating thermal resistance is important in the long-term reliability of an Actel FPGA. Design engineers should always correlate the power consumption of the device with the maximum allowable power dissipation of the package selected for that device.

Note: The junction-to-air and junction-to-board thermal resistances are based on JEDEC standard (JESD-51) and assumptions made in building the model. It may not be realized in actual application and therefore should be used with a degree of caution. Junction-to-case thermal resistance assumes that all power is dissipated through the case.

### Temperature and Voltage Derating Factors

Table 3-7 • Temperature and Voltage Derating Factors for Timing Delays (normalized to  $T_J = 70^\circ\text{C}$ ,  $V_{CC} = 1.425 \text{ V}$ )

Array Voltage $V_{CC}$ (V)	Junction Temperature ( $^\circ\text{C}$ )					
	-40 $^\circ\text{C}$	0 $^\circ\text{C}$	25 $^\circ\text{C}$	70 $^\circ\text{C}$	85 $^\circ\text{C}$	110 $^\circ\text{C}$
1.425	0.88	0.93	0.95	1.00	1.02	1.05
1.500	0.83	0.88	0.90	0.95	0.96	0.99
1.575	0.80	0.85	0.87	0.91	0.93	0.96

## Calculating Power Dissipation

### Quiescent Supply Current

**Table 3-8 • Quiescent Supply Current Characteristics ( $I_{DDQ}$ )<sup>1</sup>**

Parameter	Conditions and Modes	U1AFS250	U1AFS600	U1AFS1500
$I_{DC1}$	Maximum in operating mode (85°C) <sup>1</sup>	30 mA	45 mA	TBD
	Maximum in operating mode (70°C) <sup>1</sup>	20 mA	30 mA	TBD
	Typical in operating mode (25°C) <sup>1</sup>	3 mA	5 mA	TBD
$I_{DC2}$	Typical in standby mode (25°C) <sup>2,4</sup>	200 $\mu$ A	200 $\mu$ A	TBD
$I_{DC3}$	Typical in sleep mode (25°C) <sup>3,4</sup>	10 $\mu$ A	10 $\mu$ A	TBD

**Notes:**

- $I_{DC1}$  includes  $V_{CC}$ ,  $V_{PUMP}$ , and  $V_{CCI}$  currents. Values do not include I/O static contribution, which is shown in Table 3-9 on page 3-11 and Table 3-10 on page 3-13.
- $I_{DC2}$  represents the current from the  $V_{CC33A}$  and  $V_{CCI}$  supplies when the RTC (and the 32 kHz crystal oscillator) is ON, the FPGA is OFF, and the voltage regulator is OFF.
- $I_{DC3}$  represents the current from the  $V_{CC33A}$  and  $V_{CCI}$  supplies when the RTC (and the crystal oscillator), the FPGA, and the voltage regulator are OFF.
- $V_{CCI}$  supply is ON, since the east and west I/O banks are not cold-sparable. Values do not include I/O static contribution, which is shown in Table 3-9 on page 3-11 and Table 3-10 on page 3-13.

## Power per I/O Pin

**Table 3-9 • Summary of I/O Input Buffer Power (per pin)—Default I/O Software Settings**

	V <sub>CC1</sub> (V)	Static Power P <sub>DC7</sub> (mW) <sup>1</sup>	Dynamic Power P <sub>AC9</sub> (μW/MHz) <sup>2</sup>
<b>Applicable to Pro I/O Banks</b>			
<b>Single-Ended</b>			
3.3 V LVTTTL/LVCMOS	3.3	–	17.39
3.3 V LVTTTL/LVCMOS – Schmitt trigger	3.3	–	25.51
2.5 V LVCMOS	2.5	–	5.76
2.5 V LVCMOS – Schmitt trigger	2.5	–	7.16
1.8 V LVCMOS	1.8	–	2.72
1.8 V LVCMOS – Schmitt trigger	1.8	–	2.80
1.5 V LVCMOS (JESD8-11)	1.5	–	2.08
1.5 V LVCMOS (JESD8-11) – Schmitt trigger	1.5	–	2.00
3.3 V PCI	3.3	–	18.82
3.3 V PCI – Schmitt trigger	3.3	–	20.12
3.3 V PCI-X	3.3	–	18.82
3.3 V PCI-X – Schmitt trigger	3.3	–	20.12
<b>Voltage-Referenced</b>			
3.3 V GTL	3.3	2.90	8.23
2.5 V GTL	2.5	2.13	4.78
3.3 V GTL+	3.3	2.81	4.14
2.5 V GTL+	2.5	2.57	3.71
HSTL (I)	1.5	0.17	2.03
HSTL (II)	1.5	0.17	2.03
SSTL2 (I)	2.5	1.38	4.48
SSTL2 (II)	2.5	1.38	4.48
SSTL3 (I)	3.3	3.21	9.26
SSTL3 (II)	3.3	3.21	9.26
<b>Differential</b>			
LVDS	2.5	2.26	1.50
LVPECL	3.3	5.71	2.17

**Notes:**

1. P<sub>DC7</sub> is the static power (where applicable) measured on V<sub>CC1</sub>.
2. P<sub>AC9</sub> is the total dynamic power measured on V<sub>CC</sub> and V<sub>CC1</sub>.

**Table 3-9 • Summary of I/O Input Buffer Power (per pin)—Default I/O Software Settings (continued)**

	$V_{CCI}$ (V)	Static Power $P_{DC7}$ (mW) <sup>1</sup>	Dynamic Power $P_{AC9}$ ( $\mu$ W/MHz) <sup>2</sup>
<b>Applicable to Advanced I/O Banks</b>			
<b>Single-Ended</b>			
3.3 V LVTTTL/LVCMOS	3.3	–	16.69
2.5 V LVCMOS	2.5	–	5.12
1.8 V LVCMOS	1.8	–	2.13
1.5 V LVCMOS (JESD8-11)	1.5	–	1.45
3.3 V PCI	3.3	–	18.11
3.3 V PCI-X	3.3	–	18.11
<b>Differential</b>			
LVDS	2.5	2.26	1.20
LVPECL	3.3	5.72	1.87
<b>Applicable to Standard I/O Banks</b>			
3.3 V LVTTTL/LVCMOS	3.3	–	16.79
2.5 V LVCMOS	2.5	–	5.19
1.8 V LVCMOS	1.8	–	2.18
1.5 V LVCMOS (JESD8-11)	1.5	–	1.52

**Notes:**

1.  $P_{DC7}$  is the static power (where applicable) measured on  $V_{CCI}$ .
2.  $P_{AC9}$  is the total dynamic power measured on  $V_{CC}$  and  $V_{CCI}$ .

**Table 3-10 • Summary of I/O Output Buffer Power (per pin)—Default I/O Software Settings<sup>1</sup>**

	$C_{LOAD}$ (pF)	$V_{CCI}$ (V)	Static Power $P_{DC8}$ (mW) <sup>2</sup>	Dynamic Power $P_{AC10}$ ( $\mu$ W/MHz) <sup>3</sup>
<b>Applicable to Pro I/O Banks</b>				
<b>Single-Ended</b>				
3.3 V LVTTTL/LVCMOS	35	3.3	–	474.70
2.5 V LVCMOS	35	2.5	–	270.73
1.8 V LVCMOS	35	1.8	–	151.78
1.5 V LVCMOS (JESD8-11)	35	1.5	–	104.55
3.3 V PCI	10	3.3	–	204.61
3.3 V PCI-X	10	3.3	–	204.61
<b>Voltage-Referenced</b>				
3.3 V GTL	10	3.3	–	24.08
2.5 V GTL	10	2.5	–	13.52
3.3 V GTL+	10	3.3	–	24.10
2.5 V GTL+	10	2.5	–	13.54
HSTL (I)	20	1.5	7.08	26.22
HSTL (II)	20	1.5	13.88	27.22
SSTL2 (I)	30	2.5	16.69	105.56
SSTL2 (II)	30	2.5	25.91	116.60
SSTL3 (I)	30	3.3	26.02	114.87
SSTL3 (II)	30	3.3	42.21	131.76
<b>Differential</b>				
LVDS	–	2.5	7.70	89.62
LVPECL	–	3.3	19.42	168.02
<b>Applicable to Advanced I/O Banks</b>				
<b>Single-Ended</b>				
3.3 V LVTTTL / 3.3 V LVCMOS	35	3.3	–	468.67
2.5 V LVCMOS	35	2.5	–	267.48
1.8 V LVCMOS	35	1.8	–	149.46
1.5 V LVCMOS (JESD8-11)	35	1.5	–	103.12
3.3 V PCI	10	3.3	–	201.02
3.3 V PCI-X	10	3.3	–	201.02

**Notes:**

1. Dynamic power consumption is given for standard load and software-default drive strength and output slew.
2.  $P_{DC8}$  is the static power (where applicable) measured on  $V_{CCI}$ .
3.  $P_{AC10}$  is the total dynamic power measured on  $V_{CC}$  and  $V_{CCI}$ .

**Table 3-10 • Summary of I/O Output Buffer Power (per pin)—Default I/O Software Settings<sup>1</sup> (continued)**

	$C_{LOAD}$ (pF)	$V_{CCI}$ (V)	Static Power $P_{DC8}$ (mW) <sup>2</sup>	Dynamic Power $P_{AC10}$ ( $\mu$ W/MHz) <sup>3</sup>
<b>Differential</b>				
LVDS	–	2.5	7.74	88.92
LVPECL	–	3.3	19.54	166.52
<b>Applicable to Standard I/O Banks</b>				
<b>Single-Ended</b>				
3.3 V LVTTTL / 3.3 V LVCMOS	35	3.3	–	431.08
2.5 V LVCMOS	35	2.5	–	247.36
1.8 V LVCMOS	35	1.8	–	128.46
1.5 V LVCMOS (JESD8-11)	35	1.5	–	89.46

**Notes:**

1. Dynamic power consumption is given for standard load and software-default drive strength and output slew.
2.  $P_{DC8}$  is the static power (where applicable) measured on  $V_{CCI}$ .
3.  $P_{AC10}$  is the total dynamic power measured on  $V_{CC}$  and  $V_{CCI}$ .

## Dynamic Power Consumption of Various Internal Resources

**Table 3-11 • Different Components Contributing to the Dynamic Power Consumption in MicroBlade-Based Fusion Devices**

Parameter	Definition	Power Supply		Device-Specific Dynamic Contributions			Units
		Name	Setting	U1AFS1500	U1AFS600	U1AFS250	
P <sub>AC1</sub>	Clock contribution of a Global Rib	V <sub>CC</sub>	1.5 V	14.5	12.8	11	μW/MHz
P <sub>AC2</sub>	Clock contribution of a Global Spine	V <sub>CC</sub>	1.5 V	2.5	1.9	1.6	μW/MHz
P <sub>AC3</sub>	Clock contribution of a VersaTile row	V <sub>CC</sub>	1.5 V	0.81			μW/MHz
P <sub>AC4</sub>	Clock contribution of a VersaTile used as a sequential module	V <sub>CC</sub>	1.5 V	0.11			μW/MHz
P <sub>AC5</sub>	First contribution of a VersaTile used as a sequential module	V <sub>CC</sub>	1.5 V	0.07			μW/MHz
P <sub>AC6</sub>	Second contribution of a VersaTile used as a sequential module	V <sub>CC</sub>	1.5 V	0.29			μW/MHz
P <sub>AC7</sub>	Contribution of a VersaTile used as a combinatorial module	V <sub>CC</sub>	1.5 V	0.29			μW/MHz
P <sub>AC8</sub>	Average contribution of a routing net	V <sub>CC</sub>	1.5 V	0.70			μW/MHz
P <sub>AC9</sub>	Contribution of an I/O input pin (standard dependent)	VMV/ V <sub>CC</sub>	See Table 3-9 on page 3-11				
P <sub>AC10</sub>	Contribution of an I/O output pin (standard dependent)	V <sub>CC</sub> / V <sub>CC</sub>	See Table 3-10 on page 3-13				
P <sub>AC11</sub>	Average contribution of a RAM block during a read operation	V <sub>CC</sub>	1.5 V	25			μW/MHz
P <sub>AC12</sub>	Average contribution of a RAM block during a write operation	V <sub>CC</sub>	1.5 V	30			μW/MHz
P <sub>AC13</sub>	Dynamic Contribution for PLL	V <sub>CC</sub>	1.5 V	2.6			μW/MHz
P <sub>AC15</sub>	Contribution of NVM block during a read operation (F < 33MHz)	V <sub>CC</sub>	1.5 V	358			μW/MHz
P <sub>AC16</sub>	1st contribution of NVM block during a read operation (F > 33MHz)	V <sub>CC</sub>	1.5 V	12.88			mW
P <sub>AC17</sub>	2nd contribution of NVM block during a read operation (F > 33MHz)	V <sub>CC</sub>	1.5 V	4.8			μW/MHz
P <sub>AC18</sub>	Crystal Oscillator contribution	V <sub>CC33A</sub>	3.3 V	0.63			mW
P <sub>AC19</sub>	RC Oscillator contribution	V <sub>CC33A</sub>	3.3 V	3.3			mW
P <sub>AC20</sub>	Analog Block dynamic power contribution of ADC	V <sub>CC</sub>	1.5 V	3			mW

## Static Power Consumption of Various Internal Resources

**Table 3-12 • Different Components Contributing to the Static Power Consumption in Fusion Devices**

Parameter	Definition	Power Supply		Device-Specific Static Contributions			Units
				U1AFS1500	U1AFS600	U1AFS250	
P <sub>DC1</sub>	Core static power contribution in operating mode	V <sub>CC</sub>	1.5 V	TBD	7.5	4.50	mW
P <sub>DC2</sub>	Device static power contribution in standby mode	V <sub>CC33A</sub>	3.3 V	0.66			mW
P <sub>DC3</sub>	Device static power contribution in sleep mode	V <sub>CC33A</sub>	3.3 V	0.03			mW
P <sub>DC4</sub>	NVM static power contribution	V <sub>CC</sub>	1.5 V	1.19			mW
P <sub>DC5</sub>	Analog Block static power contribution of ADC	V <sub>CC33A</sub>	3.3 V	8.25			mW
P <sub>DC6</sub>	Analog Block static power contribution per Quad	V <sub>CC33A</sub>	3.3 V	3.3			mW
P <sub>DC7</sub>	Static contribution per input pin – standard-dependent contribution	VMV/V <sub>CC</sub>	See Table 3-9 on page 3-11				
P <sub>DC8</sub>	Static contribution per input pin – standard-dependent contribution	VMV/V <sub>CC</sub>	See Table 3-10 on page 3-13				
P <sub>DC9</sub>	Static contribution for PLL	V <sub>CC</sub>	1.5 V	2.55			mW

## Power Calculation Methodology

This section describes a simplified method to estimate power consumption of an application. For more accurate and detailed power estimations, use the SmartPower tool in the Libero IDE software.

The power calculation methodology described below uses the following variables:

- The number of PLLs as well as the number and the frequency of each output clock generated
- The number of combinatorial and sequential cells used in the design
- The internal clock frequencies
- The number and the standard of I/O pins used in the design
- The number of RAM blocks used in the design
- The number of NVM blocks used in the design
- The number of Analog Quads used in the design
- Toggle rates of I/O pins as well as VersaTiles—guidelines are provided in [Table 3-13 on page 3-21](#).
- Enable rates of output buffers—guidelines are provided for typical applications in [Table 3-14 on page 3-21](#).
- Read rate and write rate to the RAM—guidelines are provided for typical applications in [Table 3-14 on page 3-21](#).
- Read rate to the NVM blocks

The calculation should be repeated for each clock domain defined in the design.

### Methodology

#### Total Power Consumption— $P_{TOTAL}$

##### *Operating Mode, Standby Mode, and Sleep Mode*

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$P_{STAT}$  is the total static power consumption.

$P_{DYN}$  is the total dynamic power consumption.

#### Total Static Power Consumption— $P_{STAT}$

##### *Operating Mode*

$$P_{STAT} = P_{DC1} + (N_{NVM-BLOCKS} * P_{DC4}) + P_{DC5} + (N_{QUADS} * P_{DC6}) + (N_{INPUTS} * P_{DC7}) + (N_{OUTPUTS} * P_{DC8}) + (N_{PLLs} * P_{DC9})$$

$N_{NVM-BLOCKS}$  is the number of NVM blocks available in the device.

$N_{QUADS}$  is the number of Analog Quads used in the design.

$N_{INPUTS}$  is the number of I/O input buffers used in the design.

$N_{OUTPUTS}$  is the number of I/O output buffers used in the design.

$N_{PLLs}$  is the number of PLLs available in the device.

##### *Standby Mode*

$$P_{STAT} = P_{DC2}$$

##### *Sleep Mode*

$$P_{STAT} = P_{DC3}$$

#### Total Dynamic Power Consumption— $P_{DYN}$

##### *Operating Mode*

$$P_{DYN} = P_{CLOCK} + P_{S-CELL} + P_{C-CELL} + P_{NET} + P_{INPUTS} + P_{OUTPUTS} + P_{MEMORY} + P_{PLL} + P_{NVM} + P_{XTL-OSC} + P_{RC-OSC} + P_{AB}$$

**Standby Mode**

$$P_{DYN} = P_{XTL-OSC}$$

**Sleep Mode**

$$P_{DYN} = 0 \text{ W}$$

**Global Clock Dynamic Contribution— $P_{CLOCK}$**

**Operating Mode**

$$P_{CLOCK} = (P_{AC1} + N_{SPINE} * P_{AC2} + N_{ROW} * P_{AC3} + N_{S-CELL} * P_{AC4}) * F_{CLK}$$

$N_{SPINE}$  is the number of global spines used in the user design—guidelines are provided in [Table 3-13 on page 3-21](#).

$N_{ROW}$  is the number of VersaTile rows used in the design—guidelines are provided in [Table 3-13 on page 3-21](#).

$F_{CLK}$  is the global clock signal frequency.

$N_{S-CELL}$  is the number of VersaTiles used as sequential modules in the design.

**Standby Mode and Sleep Mode**

$$P_{CLOCK} = 0 \text{ W}$$

**Sequential Cells Dynamic Contribution— $P_{S-CELL}$**

**Operating Mode**

$$P_{S-CELL} = N_{S-CELL} * (P_{AC5} + (\alpha_1 / 2) * P_{AC6}) * F_{CLK}$$

$N_{S-CELL}$  is the number of VersaTiles used as sequential modules in the design. When a multi-tile sequential cell is used, it should be accounted for as 1.

$\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in [Table 3-13 on page 3-21](#).

$F_{CLK}$  is the global clock signal frequency.

**Standby Mode and Sleep Mode**

$$P_{S-CELL} = 0 \text{ W}$$

**Combinatorial Cells Dynamic Contribution— $P_{C-CELL}$**

**Operating Mode**

$$P_{C-CELL} = N_{C-CELL} * (\alpha_1 / 2) * P_{AC7} * F_{CLK}$$

$N_{C-CELL}$  is the number of VersaTiles used as combinatorial modules in the design.

$\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in [Table 3-13 on page 3-21](#).

$F_{CLK}$  is the global clock signal frequency.

**Standby Mode and Sleep Mode**

$$P_{C-CELL} = 0 \text{ W}$$

Routing Net Dynamic Contribution— $P_{NET}$

**Operating Mode**

$$P_{NET} = (N_{S-CELL} + N_{C-CELL}) * (\alpha_1 / 2) * P_{AC8} * F_{CLK}$$

$N_{S-CELL}$  is the number VersaTiles used as sequential modules in the design.

$N_{C-CELL}$  is the number of VersaTiles used as combinatorial modules in the design.

$\alpha_1$  is the toggle rate of VersaTile outputs—guidelines are provided in [Table 3-13 on page 3-21](#).

$F_{CLK}$  is the global clock signal frequency.

**Standby Mode and Sleep Mode**

$$P_{NET} = 0 \text{ W}$$

**I/O Input Buffer Dynamic Contribution— $P_{INPUTS}$**

**Operating Mode**

$$P_{INPUTS} = N_{INPUTS} * (\alpha_2 / 2) * P_{AC9} * F_{CLK}$$

$N_{INPUTS}$  is the number of I/O input buffers used in the design.

$\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in [Table 3-13 on page 3-21](#).

$F_{CLK}$  is the global clock signal frequency.

**Standby Mode and Sleep Mode**

$$P_{INPUTS} = 0 \text{ W}$$

**I/O Output Buffer Dynamic Contribution— $P_{OUTPUTS}$**

**Operating Mode**

$$P_{OUTPUTS} = N_{OUTPUTS} * (\alpha_2 / 2) * \beta_1 * P_{AC10} * F_{CLK}$$

$N_{OUTPUTS}$  is the number of I/O output buffers used in the design.

$\alpha_2$  is the I/O buffer toggle rate—guidelines are provided in [Table 3-13 on page 3-21](#).

$\beta_1$  is the I/O buffer enable rate—guidelines are provided in [Table 3-14 on page 3-21](#).

$F_{CLK}$  is the global clock signal frequency.

**Standby Mode and Sleep Mode**

$$P_{OUTPUTS} = 0 \text{ W}$$

**RAM Dynamic Contribution— $P_{MEMORY}$**

**Operating Mode**

$$P_{MEMORY} = (N_{BLOCKS} * P_{AC11} * \beta_2 * F_{READ-CLOCK}) + (N_{BLOCKS} * P_{AC12} * \beta_3 * F_{WRITE-CLOCK})$$

$N_{BLOCKS}$  is the number of RAM blocks used in the design.

$F_{READ-CLOCK}$  is the memory read clock frequency.

$\beta_2$  is the RAM enable rate for read operations—guidelines are provided in [Table 3-14 on page 3-21](#).

$\beta_3$  is the RAM enable rate for write operations—guidelines are provided in [Table 3-14 on page 3-21](#).

$F_{WRITE-CLOCK}$  is the memory write clock frequency.

**Standby Mode and Sleep Mode**

$$P_{MEMORY} = 0 \text{ W}$$

**PLL/CCC Dynamic Contribution— $P_{PLL}$**

**Operating Mode**

$$P_{PLL} = P_{AC13} * F_{CLKOUT}$$

$F_{CLKIN}$  is the input clock frequency.

$F_{CLKOUT}$  is the output clock frequency.<sup>1</sup>

**Standby Mode and Sleep Mode**

$$P_{PLL} = 0 \text{ W}$$

1. The PLL dynamic contribution depends on the input clock frequency, the number of output clock signals generated by the PLL, and the frequency of each output clock. If a PLL is used to generate more than one output clock, include each output clock in the formula output clock by adding its corresponding contribution ( $P_{AC14} * F_{CLKOUT}$  product) to the total PLL contribution.

### Nonvolatile Memory Dynamic Contribution— $P_{NVM}$

#### *Operating Mode*

The NVM dynamic power consumption is a piecewise linear function of frequency.

$$P_{NVM} = N_{NVM-BLOCKS} * \beta_4 * P_{AC15} * F_{READ-NVM} \text{ when } F_{READ-NVM} \leq 33 \text{ MHz,}$$

$$P_{NVM} = N_{NVM-BLOCKS} * \beta_4 * (P_{AC16} + P_{AC17} * F_{READ-NVM}) \text{ when } F_{READ-NVM} > 33 \text{ MHz}$$

$N_{NVM-BLOCKS}$  is the number of NVM blocks used in the design (2 in U1AFS600).

$\beta_4$  is the NVM enable rate for read operations. Default is 0 (NVM mainly in idle state).

$F_{READ-NVM}$  is the NVM read clock frequency.

#### *Standby Mode and Sleep Mode*

$$P_{NVM} = 0 \text{ W}$$

### Crystal Oscillator Dynamic Contribution— $P_{XTL-OSC}$

#### *Operating Mode*

$$P_{XTL-OSC} = P_{AC18}$$

#### *Standby Mode*

$$P_{XTL-OSC} = P_{AC18}$$

#### *Sleep Mode*

$$P_{XTL-OSC} = 0 \text{ W}$$

### RC Oscillator Dynamic Contribution— $P_{RC-OSC}$

#### *Operating Mode*

$$P_{RC-OSC} = P_{AC19}$$

#### *Standby Mode and Sleep Mode*

$$P_{RC-OSC} = 0 \text{ W}$$

### Analog System Dynamic Contribution— $P_{AB}$

#### *Operating Mode*

$$P_{AB} = P_{AC20}$$

#### *Standby Mode and Sleep Mode*

$$P_{AB} = 0 \text{ W}$$

## Guidelines

### Toggle Rate Definition

A toggle rate defines the frequency of a net or logic element relative to a clock. It is a percentage. If the toggle rate of a net is 100%, this means that the net switches at half the clock frequency. Below are some examples:

- The average toggle rate of a shift register is 100%, as all flip-flop outputs toggle at half of the clock frequency.
- The average toggle rate of an 8-bit counter is 25%:
  - Bit 0 (LSB) = 100%
  - Bit 1 = 50%
  - Bit 2 = 25%
  - ...
  - Bit 7 (MSB) = 0.78125%
  - Average toggle rate =  $(100\% + 50\% + 25\% + 12.5\% + \dots + 0.78125\%) / 8$ .

### Enable Rate Definition

Output enable rate is the average percentage of time during which tristate outputs are enabled. When non-tristate output buffers are used, the enable rate should be 100%.

**Table 3-13 • Toggle Rate Guidelines Recommended for Power Calculation**

Component	Definition	Guideline
$\alpha_1$	Toggle rate of VersaTile outputs	10%
$\alpha_2$	I/O buffer toggle rate	10%

**Table 3-14 • Enable Rate Guidelines Recommended for Power Calculation**

Component	Definition	Guideline
$\beta_1$	I/O output buffer enable rate	100%
$\beta_2$	RAM enable rate for read operations	12.5%
$\beta_3$	RAM enable rate for write operations	12.5%
$\beta_4$	NVM enable rate for read operations	0%

### Example of Power Calculation

This example considers a shift register with 5,000 storage tiles, including a counter and memory that stores analog information. The shift register is clocked at 50 MHz and stores and reads information from a RAM.

The device used is a commercial U1AF5600 device operating in typical conditions.

The calculation below uses the power calculation methodology previously presented and shows how to determine the dynamic and static power consumption of resources used in the application.

Also included in the example is the calculation of power consumption in operating, standby, and sleep modes to illustrate the benefit of power-saving modes.

#### Global Clock Contribution— $P_{\text{CLOCK}}$

$$F_{\text{CLK}} = 50 \text{ MHz}$$

$$\text{Number of sequential VersaTiles: } N_{\text{S-CELL}} = 5,000$$

$$\text{Estimated number of Spines: } N_{\text{SPINES}} = 5$$

$$\text{Estimated number of Rows: } N_{\text{ROW}} = 313$$

#### Operating Mode

$$P_{\text{CLOCK}} = (P_{\text{AC1}} + N_{\text{SPINE}} * P_{\text{AC2}} + N_{\text{ROW}} * P_{\text{AC3}} + N_{\text{S-CELL}} * P_{\text{AC4}}) * F_{\text{CLK}}$$

$$P_{\text{CLOCK}} = (0.0128 + 5 * 0.0019 + 313 * 0.00081 + 5,000 * 0.00011) * 50$$

$$P_{\text{CLOCK}} = 41.28 \text{ mW}$$

#### Standby Mode and Sleep Mode

$$P_{\text{CLOCK}} = 0 \text{ W}$$

#### Logic—Sequential Cells, Combinational Cells, and Routing Net Contributions— $P_{\text{S-CELL}}$ , $P_{\text{C-CELL}}$ , and $P_{\text{NET}}$

$$F_{\text{CLK}} = 50 \text{ MHz}$$

$$\text{Number of sequential VersaTiles: } N_{\text{S-CELL}} = 5,000$$

$$\text{Number of combinatorial VersaTiles: } N_{\text{C-CELL}} = 6,000$$

$$\text{Estimated toggle rate of VersaTile outputs: } \alpha_1 = 0.1 \text{ (10\%)}$$

#### Operating Mode

$$P_{\text{S-CELL}} = N_{\text{S-CELL}} * (P_{\text{AC5}} + (\alpha_1 / 2) * P_{\text{AC6}}) * F_{\text{CLK}}$$

$$P_{\text{S-CELL}} = 5,000 * (0.00007 + (0.1 / 2) * 0.00029) * 50$$

$$P_{\text{S-CELL}} = 21.13 \text{ mW}$$

$$P_{\text{C-CELL}} = N_{\text{C-CELL}} * (\alpha_1 / 2) * P_{\text{AC7}} * F_{\text{CLK}}$$

$$P_{\text{C-CELL}} = 6,000 * (0.1 / 2) * 0.00029 * 50$$

$$P_{\text{C-CELL}} = 4.35 \text{ mW}$$

$$P_{\text{NET}} = (N_{\text{S-CELL}} + N_{\text{C-CELL}}) * (\alpha_1 / 2) * P_{\text{AC8}} * F_{\text{CLK}}$$

$$P_{\text{NET}} = (5,000 + 6,000) * (0.1 / 2) * 0.0007 * 50$$

$$P_{\text{NET}} = 19.25 \text{ mW}$$

$$P_{\text{LOGIC}} = P_{\text{S-CELL}} + P_{\text{C-CELL}} + P_{\text{NET}}$$

$$P_{\text{LOGIC}} = 21.13 \text{ mW} + 4.35 \text{ mW} + 19.25 \text{ mW}$$

$$P_{\text{LOGIC}} = 44.73 \text{ mW}$$

#### Standby Mode and Sleep Mode

$$P_{S-CELL} = 0 \text{ W}$$

$$P_{C-CELL} = 0 \text{ W}$$

$$P_{NET} = 0 \text{ W}$$

$$P_{LOGIC} = 0 \text{ W}$$

### I/O Input and Output Buffer Contribution— $P_{I/O}$

This example uses LVTTTL 3.3 V I/O cells. The output buffers are 12 mA-capable, configured with high output slew and driving a 35 pF output load.

$$F_{CLK} = 50 \text{ MHz}$$

$$\text{Number of input pins used: } N_{INPUTS} = 30$$

$$\text{Number of output pins used: } N_{OUTPUTS} = 40$$

$$\text{Estimated I/O buffer toggle rate: } \alpha_2 = 0.1 \text{ (10\%)}$$

$$\text{Estimated IO buffer enable rate: } \beta_1 = 1 \text{ (100\%)}$$

#### Operating Mode

$$P_{INPUTS} = N_{INPUTS} * (\alpha_2 / 2) * P_{AC9} * F_{CLK}$$

$$P_{INPUTS} = 30 * (0.1 / 2) * 0.01739 * 50$$

$$P_{INPUTS} = 1.30 \text{ mW}$$

$$P_{OUTPUTS} = N_{OUTPUTS} * (\alpha_2 / 2) * \beta_1 * P_{AC10} * F_{CLK}$$

$$P_{OUTPUTS} = 40 * (0.1 / 2) * 1 * 0.4747 * 50$$

$$P_{OUTPUTS} = 47.47 \text{ mW}$$

$$P_{I/O} = P_{INPUTS} + P_{OUTPUTS}$$

$$P_{I/O} = 1.30 \text{ mW} + 47.47 \text{ mW}$$

$$P_{I/O} = 48.77 \text{ mW}$$

#### Standby Mode and Sleep Mode

$$P_{INPUTS} = 0 \text{ W}$$

$$P_{OUTPUTS} = 0 \text{ W}$$

$$P_{I/O} = 0 \text{ W}$$

### RAM Contribution— $P_{MEMORY}$

$$\text{Frequency of Read Clock: } F_{READ-CLOCK} = 10 \text{ MHz}$$

$$\text{Frequency of Write Clock: } F_{WRITE-CLOCK} = 10 \text{ MHz}$$

$$\text{Number of RAM blocks: } N_{BLOCKS} = 20$$

$$\text{Estimated RAM Read Enable Rate: } \beta_2 = 0.125 \text{ (12.5\%)}$$

$$\text{Estimated RAM Write Enable Rate: } \beta_3 = 0.125 \text{ (12.5\%)}$$

#### Operating Mode

$$P_{MEMORY} = (N_{BLOCKS} * P_{AC11} * \beta_2 * F_{READ-CLOCK}) + (N_{BLOCKS} * P_{AC12} * \beta_3 * F_{WRITE-CLOCK})$$

$$P_{MEMORY} = (20 * 0.025 * 0.125 * 10) + (20 * 0.030 * 0.125 * 10)$$

$$P_{MEMORY} = 1.38 \text{ mW}$$

#### Standby Mode and Sleep Mode

$$P_{MEMORY} = 0 \text{ W}$$

### PLL/CCC Contribution— $P_{PLL}$

PLL is not used in this application.

$$P_{PLL} = 0 \text{ W}$$

**Nonvolatile Memory— $P_{NVM}$**

Nonvolatile memory is not used in this application.

$$P_{NVM} = 0 \text{ W}$$

**Crystal Oscillator— $P_{XTL-OSC}$**

The application utilizes standby mode. The crystal oscillator is assumed to be active.

**Operating Mode**

$$P_{XTL-OSC} = P_{AC18}$$

$$P_{XTL-OSC} = 0.63 \text{ mW}$$

**Standby Mode**

$$P_{XTL-OSC} = P_{AC18}$$

$$P_{XTL-OSC} = 0.63 \text{ mW}$$

**Sleep Mode**

$$P_{XTL-OSC} = 0 \text{ W}$$

**RC Oscillator— $P_{RC-OSC}$**

**Operating Mode**

$$P_{RC-OSC} = P_{AC19}$$

$$P_{RC-OSC} = 3.30 \text{ mW}$$

**Standby Mode and Sleep Mode**

$$P_{RC-OSC} = 0 \text{ W}$$

**Analog System— $P_{AB}$**

Number of Quads used:  $N_{QUADS} = 4$

**Operating Mode**

$$P_{AB} = P_{AC20}$$

$$P_{AB} = 3.00 \text{ mW}$$

**Standby Mode and Sleep Mode**

$$P_{AB} = 0 \text{ W}$$

**Total Dynamic Power Consumption— $P_{DYN}$**

**Operating Mode**

$$P_{DYN} = P_{CLOCK} + P_{S-CELL} + P_{C-CELL} + P_{NET} + P_{INPUTS} + P_{OUTPUTS} + P_{MEMORY} + P_{PLL} + P_{NVM} + P_{XTL-OSC} + P_{RC-OSC} + P_{AB}$$

$$P_{DYN} = 41.28 \text{ mW} + 21.1 \text{ mW} + 4.35 \text{ mW} + 19.25 \text{ mW} + 1.30 \text{ mW} + 47.47 \text{ mW} + 1.38 \text{ mW} + 0 + 0 + 0.63 \text{ mW} + 3.30 \text{ mW} + 3.00 \text{ mW}$$

$$P_{DYN} = 143.06 \text{ mW}$$

**Standby Mode**

$$P_{DYN} = P_{XTL-OSC}$$

$$P_{DYN} = 0.63 \text{ mW}$$

**Sleep Mode**

$$P_{DYN} = 0 \text{ W}$$

### Total Static Power Consumption— $P_{STAT}$

Number of Quads used:  $N_{QUADS} = 4$

Number of NVM blocks available (U1AF5600):  $N_{NVM-BLOCKS} = 2$

Number of input pins used:  $N_{INPUTS} = 30$

Number of output pins used:  $N_{OUTPUTS} = 40$

#### Operating Mode

$$P_{STAT} = P_{DC1} + (N_{NVM-BLOCKS} * P_{DC4}) + P_{DC5} + (N_{QUADS} * P_{DC6}) + (N_{INPUTS} * P_{DC7}) + (N_{OUTPUTS} * P_{DC8})$$

$$P_{STAT} = 7.50 \text{ mW} + (2 * 1.19 \text{ mW}) + 8.25 \text{ mW} + (4 * 3.30 \text{ mW}) + (30 * 0.00) + (40 * 0.00)$$

$$P_{STAT} = 31.33 \text{ mW}$$

#### Standby Mode

$$P_{STAT} = P_{DC2}$$

$$P_{STAT} = 0.03 \text{ mW}$$

#### Sleep Mode

$$P_{STAT} = P_{DC3}$$

$$P_{STAT} = 0.03 \text{ mW}$$

### Total Power Consumption— $P_{TOTAL}$

In operating mode, the total power consumption of the device is 174.39 mW:

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$$P_{TOTAL} = 143.06 \text{ mW} + 31.33 \text{ mW}$$

$$P_{TOTAL} = 174.39 \text{ mW}$$

In standby mode, the total power consumption of the device is limited to 0.66 mW:

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$$P_{TOTAL} = 0.03 \text{ mW} + 0.63 \text{ mW}$$

$$P_{TOTAL} = 0.66 \text{ mW}$$

In sleep mode, the total power consumption of the device drops as low as 0.03 mW:

$$P_{TOTAL} = P_{STAT} + P_{DYN}$$

$$P_{TOTAL} = 0.03 \text{ mW}$$

## Power Consumption

Table 3-15 • Power Consumption

Parameter	Description	Condition	Min.	Typical	Max.	Units
<b>Crystal Oscillator</b>						
I <sub>STBTAL</sub>	Standby Current of Crystal Oscillator			10		μA
I <sub>DYNXTAL</sub>	Operating Current	RC		0.6		mA
		0.032–0.2		0.19		mA
		0.2–2.0		0.6		mA
		2.0–20.0		0.6		mA
<b>RC Oscillator</b>						
I <sub>DYNRC</sub>	Operating Current			1		mA
<b>ACM</b>						
	Operating Current (fixed clock)			200		μA/MHz
	Operating Current (user clock)			30		μA
<b>NVM System</b>						
	NVM Array Operating Power	Idle		795		μA
		Read operation		See Table 3-12 on page 3-16.		See Table 3-12 on page 3-16.
		Erase		900		μA
		Write		900		μA
P <sub>NVMCTRL</sub>	NVM Controller Operating Power			20		μW/MHz

## Part Number and Revision Date

Part Number 51700104-003-0

Revised October 2008

## List of Changes

The following table lists critical changes that were made in the current version of the document. This datasheet is based on the *Actel Fusion Mixed-Signal FPGAs* datasheet. For any past Fusion datasheet changes, refer to the *Actel Fusion Mixed-Signal FPGAs* datasheet change table.

Previous Version	Changes in Current Version (Preliminary v0.4)	Page
Advance v0.3 (August 2008)	The version number category was changed from Advance to Preliminary, which means the datasheet contains information based on simulation and/or initial characterization. The information is believed to be correct, but changes are possible.	N/A
Advance v0.1 (July 2008)	The title of the datasheet changed from Actel Programmable System Chips for the MicroBlade Advanced Mezzanine Card Solution to Actel Fusion Mixed-Signal FPGAs for the MicroBlade Advanced Mezzanine Card Solution. In addition, all instances of programmable system chip were changed to mixed-signal FPGA.	N/A

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